## MSKSEMI















**ESD** 

TVS

TSS

MOV

GDT

**PLED** 

# Broduct data sheet



Semiconductor

Compiance

## VOLTAGE RANGE 50 to 600 Volts CURRENT

3.0 Amperes



**SMB** 

#### **FEATURES**

- \* Ideal for surface mount applications
- \* Easy pick and place
- \* Built-in strain relief
- \* Low forward voltage drop

#### **MECHANICAL DATA**

- \* Case: Molded plastic
- \* Epoxy: UL 94V-0 rate flame retardant
- \* Metallurgically bonded construction
- \* Polarity: Color band denotes cathode end
- \* Mounting position: Any
- \* Weight: 0.093 grams

## MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Rating 25°C ambient temperature unless otherwies specified. Single phase half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%.

| P/N(MARK)  |          | ES3AB | ES3BB    | ES3CB | ES3DB | ES3EB | ES3GB | ES3JB | UNITS |
|--|----------|-------|----------|-------|-------|-------|-------|-------|-------|
| Maximum Recurrent Peak Reverse Voltage                   |          | 50    | 100      | 150   | 200   | 300   | 400   | 600   | V     |
| Maximum RMS Voltage                                      |          | 35    | 70       | 105   | 140   | 210   | 280   | 420   | V     |
| Maximum DC Blocking Voltage                              |          | 50    | 100      | 150   | 200   | 300   | 400   | 600   | V     |
| Maximum Average Forward Rectified (                      | Current  |       |          |       |       |       |       |       |       |
| .375"(9.5mm) Lead Length at Ta=55℃                       |          |       |          |       | 3.0   |       |       |       | Α     |
| Peak Forward Surge Current, 8.3 ms single half sine-wave |          |       |          |       |       |       |       |       |       |
| superimposed on rated load (JEDEC method)                |          |       |          |       | 80    |       |       |       | Α     |
| Maximum Instantaneous Forward Voltage at 3.0A            |          |       | 1.       | 0     |       | 1.    | .4    | 1.7   | V     |
| Maximum DC Reverse Current                               | Ta=25°C  |       |          |       | 5.0   |       |       |       | uA    |
| at Rated DC Blocking Voltage                             | Ta=100°C |       |          |       | 50    |       |       |       | uA    |
| Maximum Reverse Recovery Time (Note 1)                   |          |       | 35       |       |       |       | nS    |       |       |
| Typical Junction Capacitance (Note 2)                    |          |       | 60       |       |       |       | pF    |       |       |
| Operating and Storage Temperature Range TJ, Tstg         |          |       | -65—+150 |       |       |       |       | °C    |       |

#### NOTES:

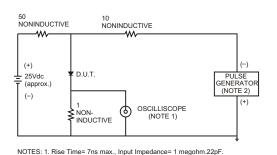
- 1. Reverse Recovery Time test condition: IF=0.5A, IR=1.0A, IRR=0.25A
- 2. Measured at 1MHz and applied reverse voltage of 4.0V D.C.





#### RATING AND CHARACTERISTIC CURVES (ES3AB THRU ES3JB)

#### FIG.1- TEST CIRCUIT DIAGRAM AND REVERSE RECOVERY TIME CHARACTERISTIC



2. Rise Time= 10ns max., Source Impedance= 50 ohms.

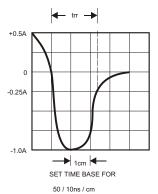


FIG.2-TYPICAL FORWARD CURRENT DERATING CURVE

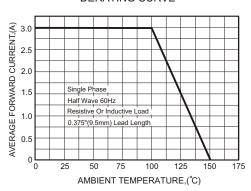


FIG.3-TYPICAL FORWARD

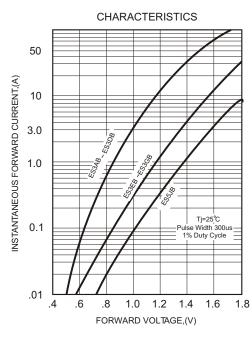


FIG.4-TYPICAL REVERSE CHARACTERISTICS 50 10 REVERSE LEAKAGE CURRENT, (A) 3.0 1.0 Tj=100°C 0.1 20 40 60 80 100 120 PERCENT OF RATED PEAK REVERSE VOLTAGE,(%)

FIG.5-MAXIMUM NON-REPETITIVE FORWARD SURGE CURRENT

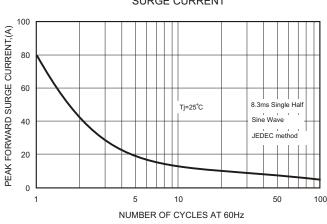
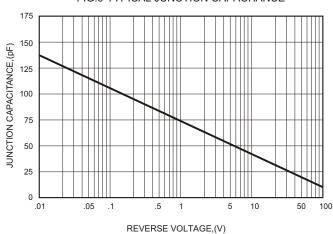


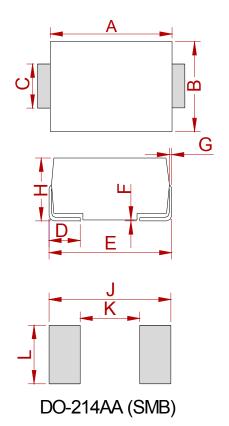
FIG.6-TYPICAL JUNCTION CAPACITANCE





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## **PACKAGE MECHANICAL DATA**



|      | 1          |        |        |       |  |  |  |
|------|------------|--------|--------|-------|--|--|--|
|      | Dimensions |        |        |       |  |  |  |
| Ref. | Millir     | neters | Inches |       |  |  |  |
|      | Min.       | Max.   | Min.   | Max.  |  |  |  |
| Α    | 4.25       | 4.75   | 0.167  | 0.187 |  |  |  |
| В    | 3.30       | 3.94   | 0.130  | 0.155 |  |  |  |
| С    | 1.85       | 2.21   | 0.073  | 0.087 |  |  |  |
| D    | 0.76       | 1.52   | 0.030  | 0.060 |  |  |  |
| Е    | 5.08       | 5.59   | 0.200  | 0.220 |  |  |  |
| F    | 0.051      | 0.203  | 0.002  | 0.008 |  |  |  |
| G    | 0.15       | 0.31   | 0.006  | 0.012 |  |  |  |
| Н    | 2.11       | 2.44   | 0.083  | 0.096 |  |  |  |
| J    | 6.80       |        | 0.270  |       |  |  |  |
| K    |            | 2.60   |        | 0.100 |  |  |  |
| L    | 2.40       |        | 0.090  |       |  |  |  |

## **REEL SPECIFICATION**

| P/N              | PKG | QTY  |
|------------------|-----|------|
| ES3AB THRU ES3JB | SMB | 3000 |



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